Apacer

The Most **Reliable** Storage For Industries

UH110-UFD4





Apacer

Overview

UH110-UFD4

Apacer's UH110-UFD4 utilizes 3D NAND for higher capacity up to 8GB and provides more power efficiency than 2D NAND, with the aim of replacing a conventional IDE hard disk drive. With exquisite size and robust metal housing, UH110-UFD4 prevents mechanical interference and has hardware mechanism to active write protection.



UH110-UFD4 is a new generation USB flash drive compatible with the latest USB specification – USB 3.1 Gen1 (SuperSpeed) Super Speed, with a maximum transfer rate of 5.0 Gbps. The connector is backward compatible with USB 2.0 and USB 1.1 interfaces. With compliance with USB 3.1 specification, this USB drive can deliver up to 265 MB/s outstanding performance.

Reliability wise, UH110-UFD4 is implemented with LDPC (Low Density Parity Check) ECC engine to extend SSD endurance and increase data reliability while reading raw data inside a flash chip. In addition, the drive comes with various implementations including powerful hardware ECC engine, Wear Leveling, flash block management, S.M.A.R.T., Page Mapping page mapping ,etc. This product is well suited for portable flash storage applications while operating at minimal power consumption.

Feature

- · Write Protect Switch
- · Adopts advanced LDPC ECC engine with 3D NAND flash memory to improve reliability
- · Global Wear Leveling
- · Flash bad-block management
- · 4K Page Mapping
- · Power Failure Management
- · S.M.A.R.T.
- · SLC-liteX
- SMART Read Refresh™

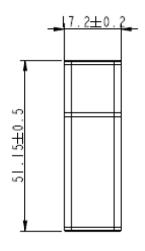


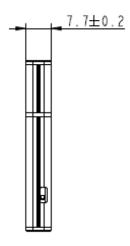
Specifications

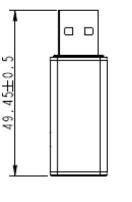
Model	UH110-UFD4
Interface	USB 3.1 Gen1
Connector	USB Type A Plug
Form Factor	USB flash drive
NAND Flash Type	3D TLC
Capacity	4GB~8GB
External DRAM	No
Sustained Read Performance (MB/sec)	Up to 265
Sustained Write Performance (MB/sec)	Up to 50
ECC Engine	Low-Density Parity-Check (LDPC) Code
IOPS (4K Random Write)	1100
Standard Operating Temperature (°C)	0 ~ + 70
Extended Operating Temperature (°C)	-40 ~ + 85 * Not supported on 4GB
Storage Temperature (°C)	-55 ~ + 100
Housing	Yes
H/W Write Protect	Yes
Shock	Operation: 50G/11ms (compliant with MIL-STD-202G) Non-operation: 1500G/0.5ms (compliant with MIL-STD-883K)
Vibration	Operation: 7.69 Grms, 20~2000 Hz/random (compliant with MIL-STD-810G) Non-operation: 4.02 Grms, 15~2000 Hz/random (compliant with MIL-STD-810G)
Operating Voltage	5.0 V ± 5%
Power Consumption	Active mode: 185 mA; Idle mode: 75 mA
Dimension (L x W x H)	51.15 x 17.2 x 7.7 (mm)
MTBF (hours)	>3,000,000

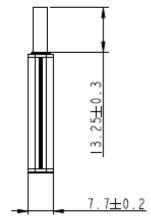


Mechanical Specification









Unit: mm

For more information, contact your Apacer representative

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